

Supporting Information

Vacuum-UV Induced DNA Strand Breaks – Influence of the Radiosensitizers 5-Bromouracil and 8-Bromo adenine

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SI.1 Overview of the cross sections for SSBs for the different non-modified and brominated DNA sequences upon VUV irradiation.

DNA sequence	Cross section for SSBs in 10 ⁻¹⁶ cm ²	Substrate	Radiation
5'-d(G ₁₂)	(2.3 ± 0.2)	CaF ₂	VUV
5'-d(TT(G ^{5Br} UG) ₃ TT)	(7.9 ± 0.4)	CaF ₂	VUV
5'-d(C ₁₂)	(1.7 ± 0.1)	CaF ₂	VUV
5'-d(TT(C ^{5Br} UC) ₃ TT)	(10.2 ± 1.1)	CaF ₂	VUV
5'-d(T ₁₂)	(2.1 ± 0.2)	CaF ₂	VUV
5'-d(TT(T ^{5Br} UT) ₃ TT)	(10.5 ± 1.3)	CaF ₂	VUV

SI.2 Overview of the cross sections for SSBs for the different DNA sequences modified with ^{5Br}U upon VUV irradiation.

DNA sequence	Cross section for SSBs in 10 ⁻¹⁶ cm ²	Substrate	Radiation
5'-d(TTG ^{5Br} UTT)	(3.9 ± 1.2)	CaF ₂	VUV
5'-d(TTGA ^{5Br} UTT)	(3.5 ± 1.3)	CaF ₂	VUV
5'-d(TTGAA ^{5Br} UTT)	(3.4 ± 0.8)	CaF ₂	VUV
5'-d(TTGAAA ^{5Br} UTT)	(3.0 ± 0.5)	CaF ₂	VUV
5'-d(TTGAAAA ^{5Br} UTT)	(3.1 ± 0.7)	CaF ₂	VUV
5'-d(TTGAAAAA ^{5Br} UTT)	(2.5 ± 0.3)	CaF ₂	VUV

SI.3 Overview of the cross sections for SSBs of the different DNA sequences modified with ^{8Br}A irradiated on two different substrates upon VUV irradiation.

DNA sequence	Cross section for SSBs in 10⁻¹⁶ cm²	Substrate	Radiation
5'-d(TT(ATA) ₃ TT)	(2.2 ± 0.7)	CaF ₂	VUV
5'-d(TT(^{8Br} ATA) ₃ TT)	(2.7 ± 0.6)	CaF ₂	VUV
5'-d(TT(ATA) ₃ TT)	(4.1 ± 0.6)	Si	VUV and indirect LEE
5'-d(TT(^{8Br} ATA) ₃ TT)	(3.9 ± 0.4)	Si	VUV and indirect LEE